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$$
\begin{aligned}
& \mathbf{V}_{\mathrm{CES}}=1200 \mathrm{~V} \\
& \mathbf{I}_{\mathrm{C}}=300 \mathrm{~A} @ \mathbf{T c}=80^{\circ} \mathrm{C}
\end{aligned}
$$

NPT IGBT Power Module

## Application

- Zero Current Switching resonant mode


## Features

- Non Punch Through (NPT) FAST IGBT
- Low voltage drop
- Low tail current
- Switching frequency up to 50 kHz
- Soft recovery parallel diodes
- Low diode VF
- Low leakage current
- RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- Symmetrical design
- M5 power connectors

- High level of integration


## Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive $\mathrm{T}_{\mathrm{C}}$ of $\mathrm{V}_{\mathrm{CEsat}}$
- Low profile
- RoHS compliant


## Absolute maximum ratings

| Parameter | Max ratings |  | Unit |  |
| :---: | :--- | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CES}}$ |  |  |  |  |
| $\mathrm{I}_{\mathrm{C}}$ | Collector - Emitter Breakdown Voltage | Continuous Collector Current |  | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 400 |
|  |  | $\mathrm{~T}_{\mathrm{c}}=80^{\circ} \mathrm{C}$ | 300 | A |
| $\mathrm{I}_{\mathrm{CM}}$ | Pulsed Collector Current | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 600 |  |
| $\mathrm{~V}_{\mathrm{GE}}$ | Gate - Emitter Voltage |  | $\pm 20$ | V |
| $\mathrm{P}_{\mathrm{D}}$ | Maximum Power Dissipation | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 1780 | W |
| RBSOA | Reverse Bias Safe Operating Area | $\mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$ | $600 \mathrm{~A} @ 1200 \mathrm{~V}$ |  |

## APTGF300U120DG

## All ratings @ $\mathrm{T}_{\mathrm{j}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Condition |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {CES }}$ | Zero Gate Voltage Collector Current | $\begin{aligned} & \mathrm{V}_{\mathrm{GE}}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=1200 \mathrm{~V} \end{aligned}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  |  | 500 | $\mu \mathrm{A}$ |
|  |  |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ |  |  | 750 |  |
| $\mathrm{V}_{\mathrm{CE} \text { (sat) }}$ | Collector Emitter saturation Voltage | $\begin{gathered} \mathrm{V}_{\mathrm{GE}}=15 \mathrm{~V} \\ \mathrm{I}_{\mathrm{C}}=300 \mathrm{~A} \end{gathered}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | 3.3 | 3.9 | V |
|  |  |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ |  | 4 |  |  |
| $\mathrm{V}_{\mathrm{GE}(\mathrm{th})}$ | Gate Threshold Voltage | $\mathrm{V}_{\mathrm{GE}}=\mathrm{V}_{\mathrm{CE}}, \mathrm{I}_{\mathrm{C}}=12 \mathrm{~mA}$ |  | 4.5 |  | 6.5 | V |
| $\mathrm{I}_{\text {GES }}$ | Gate - Emitter Leakage Current | $\mathrm{V}_{\mathrm{GE}}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\mathrm{CE}}=0 \mathrm{~V}$ |  |  |  | $\pm 1$ | $\mu \mathrm{A}$ |

## Dynamic Characteristics

| Symbol | Characteristic | Test Conditi |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\text {ies }}$ | Input Capacitance | $\begin{aligned} & \hline \mathrm{V}_{\mathrm{GE}}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=25 \mathrm{~V} \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ |  |  | 21 |  | nF |
| $\mathrm{C}_{\text {oes }}$ | Output Capacitance |  |  |  | 2.9 |  |  |
| $\mathrm{C}_{\text {res }}$ | Reverse Transfer Capacitance |  |  |  | 1.52 |  |  |
| $\mathrm{T}_{\mathrm{d}(\text { on })}$ | Turn-on Delay Time | $\begin{aligned} & \text { Inductive Switching }\left(25^{\circ} \mathrm{C}\right) \\ & \mathrm{V}_{\mathrm{GE}}=15 \mathrm{~V} \\ & \mathrm{~V}_{\text {Bus }}=600 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{C}}=300 \mathrm{~A} \\ & \mathrm{R}_{\mathrm{G}}=3 \Omega \\ & \hline \end{aligned}$ |  |  | 120 |  | ns |
| $\mathrm{T}_{\mathrm{r}}$ | Rise Time |  |  |  | 50 |  |  |
| $\mathrm{T}_{\mathrm{d} \text { (off) }}$ | Turn-off Delay Time |  |  |  | 310 |  |  |
| $\mathrm{T}_{\mathrm{f}}$ | Fall Time |  |  |  | 30 |  |  |
| $\mathrm{T}_{\mathrm{d}(\text { on) }}$ | Turn-on Delay Time | $\begin{aligned} & \text { Inductive Switching }\left(125^{\circ} \mathrm{C}\right) \\ & \mathrm{V}_{\mathrm{GE}}=15 \mathrm{~V} \\ & \mathrm{~V}_{\text {Bus }}=600 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{C}}=300 \mathrm{~A} \\ & \mathrm{R}_{\mathrm{G}}=3 \Omega \end{aligned}$ |  |  | 130 |  | ns |
| $\mathrm{T}_{\mathrm{r}}$ | Rise Time |  |  |  | 60 |  |  |
| $\mathrm{T}_{\mathrm{d} \text { (off) }}$ | Turn-off Delay Time |  |  |  | 360 |  |  |
| $\mathrm{T}_{\mathrm{f}}$ | Fall Time |  |  |  | 40 |  |  |
| $\mathrm{E}_{\text {on }}$ | Turn-on Switching Energy | $\begin{aligned} & \mathrm{V}_{\mathrm{GE}}=15 \mathrm{~V} \\ & \mathrm{~V}_{\text {Bus }}=600 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{C}}=300 \mathrm{~A} \\ & \mathrm{R}_{\mathrm{G}}=3 \Omega \\ & \hline \end{aligned}$ | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ |  | 25 |  | mJ |
| $\mathrm{E}_{\text {off }}$ | Turn-off Switching Energy |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ |  | 15 |  |  |

## Diode ratings and characteristics

| Symbol | Characteristic | Test Conditions |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {RRM }}$ | Maximum Peak Repetitive Reverse Voltage |  |  | 1200 |  |  | V |
| $\mathrm{I}_{\text {RM }}$ | Maximum Reverse Leakage Current | $\mathrm{V}_{\mathrm{R}}=1200 \mathrm{~V}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  |  | 250 | $\mu \mathrm{A}$ |
|  |  |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ |  |  | 500 |  |
| $\mathrm{I}_{\mathrm{F}}$ | DC Forward Current |  | $\mathrm{Tc}=80^{\circ} \mathrm{C}$ |  | 300 |  | A |
| $\mathrm{V}_{\mathrm{F}}$ | Diode Forward Voltage | $\mathrm{I}_{\mathrm{F}}=300 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{i}}=25^{\circ} \mathrm{C}$ |  | 2.1 |  | V |
|  |  |  | $\mathrm{T}_{\mathrm{i}}=125^{\circ} \mathrm{C}$ |  | 1.9 |  |  |
| $\mathrm{t}_{\mathrm{rr}}$ | Reverse Recovery Time | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=300 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{R}}=600 \mathrm{~V} \\ & \mathrm{di} / \mathrm{dt}=4500 \mathrm{~A} / \mu \mathrm{s} \end{aligned}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | 120 |  | ns |
|  |  |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ |  | 210 |  |  |
| $\mathrm{Q}_{\mathrm{rr}}$ | Reverse Recovery Charge |  | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | 22 |  | $\mu \mathrm{C}$ |
|  |  |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ |  | 43 |  |  |
| Er | Reverse Recovery Energy |  | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | 7 |  | mJ |
|  |  |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ |  | 15 |  |  |


| Therm | and package |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Symbol | Characteristic |  |  | Min | Typ | Max | Unit |
| $\mathrm{R}_{\text {thJC }}$ | Junction to Case Thermal Resistance |  | IGBT |  |  | 0.07 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  |  | Diode |  |  | 0.12 |  |
| $\mathrm{V}_{\text {ISOL }}$ | RMS Isolation Voltage, any terminal to case $\mathrm{t}=1 \mathrm{~min}, 50 / 60 \mathrm{~Hz}$ |  |  | 4000 |  |  | V |
| $\mathrm{T}_{\mathrm{J}}$ | Operating junction temperature range |  |  | -40 |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature Range |  |  | -40 |  | 125 |  |
| $\mathrm{T}_{\mathrm{C}}$ | Operating Case Temperature |  |  | -40 |  | 100 |  |
| Torque | Mounting torque | To heatsink | M6 | 3 |  | 5 | N.m |
|  |  | For terminals | M5 | 2 |  | 3.5 |  |
| Wt | Package Weight |  |  |  |  | 300 | g |

SP6 Package outline (dimensions in mm)


See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

## Typical Performance Curve









## APTGF300U120DG





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